NSN 5962-01-247-5647

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View Online at https://aerobasegroup.com/nsn/5962-01-247-5647

Body Length:
Between 0.540 inches and 0.560 inches
Body Width:
Between 0.442 inches and 0.458 inches
Body Height:
Between 0.060 inches and 0.120 inches
Maximum Power Dissipation Rating:
170.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
6660-01-153-1269 cloud height se
Features Provided:
Programmable and monolithic and ultraviolet erasable and high speed
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Leadless flat pack
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
17 input
Case Outline Source And Designator:
C-12 mil-m-38510
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-2.0 volts power source and 7.0 volts power source
Memory Device Type:
Rom
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
32 leadless
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:

Yes - demil/mli

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